

# CY7C1019CV33

# 1 Mbit (128K x 8) Static RAM

#### Features

- Temperature Ranges
  □ Industrial: -40°C to 85°C
  □ Automotive-A: -40°C to 85°C
- Pin and Function compatible with CY7C1019BV33
- High Speed
  - ⊡ t<sub>AA</sub> = 10 ns
- CMOS for optimum Speed and Power
- Data Retention at 2.0V
- Center Power/Ground Pinout
- Automatic Power Down when deselected
- Easy Memory Expansion with CE and OE Options
- Available in Pb-free and non Pb-free 48-Ball VFBGA, 32-Pin TSOP II and 400-mil SOJ Package

#### **Functional Description**

The CY7C1019CV33 is a high performance CMOS static RAM organized as 131,072 words by 8 bits. Easy memory expansion is provided by an active LOW Chip Enable (CE), an active LOW Output Enable (OE), and tristate drivers. This device has an automatic power down feature that significantly reduces power consumption when deselected.

Writing to the device is accomplished by taking Chip Enable  $\overline{(CE)}$  and Write Enable  $\overline{(WE)}$  inputs LOW. Data on the eight I/O pins  $(I/O_0 \text{ through } I/O_7)$  is then written into the location specified on the address pins (A<sub>0</sub> through A<sub>16</sub>).

<u>Rea</u>ding from the device is <u>ac</u>complished by taking Chip Enable  $(\overline{CE})$  and Output Enable  $(\overline{OE})$  LOW while forcing Write Enable (WE) HIGH. Under these conditions, the contents of the memory location specified by the address pins will appear on the I/O pins.

The eight input/output pins ( $I/O_0$  through  $I/O_7$ ) are placed in a high impedance state when the device is deselected (CE HIGH), the outputs are disabled (OE HIGH), or during a write operation (CE LOW, and WE LOW).



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#### **Selection Guide**

| Description               | -10 (Industrial/<br>Auto-A) | -12 (Industrial) | -15 (Industrial) | Unit |
|---------------------------|-----------------------------|------------------|------------------|------|
| Maximum Access Time       | 10                          | 12               | 15               | ns   |
| Maximum Operating Current | 80                          | 75               | 70               | mA   |
| Maximum Standby Current   | 5                           | 5                | 5                | mA   |

# **Pin Configuration**

Figure 1. 48-Ball VFBGA (Top View) <sup>[1]</sup>



Figure 2. 32-Pin SOJ/TSOP II (Top View) <sup>[1]</sup>

| $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | 32<br>31<br>30<br>29<br>28<br>27<br>26<br>25<br>24<br>23<br>20<br>19<br>18<br>17 | A <sub>16</sub><br>A <sub>15</sub><br>A <sub>14</sub><br>A <sub>13</sub><br>OE<br>I/O7<br>I/O6<br>VSS<br>VCC<br>I/O5<br>I/O4<br>A <sub>12</sub><br>A <sub>11</sub><br>A <sub>10</sub><br>A <sub>9</sub><br>A <sub>8</sub> |
|---|--|---|
|---|--|---|

#### Note 1. NC pins are not connected on the die.



V

V

V

V

## Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

| Storage Temperature65°C to +150°C   |
|---|
| Ambient Temperature with<br>Power Applied–55°C to +125°C                            |
| Supply Voltage on $V_{CC}$ to Relative $GND^{\left[2\right]}0.5V$ to +4.6V          |
| DC Voltage Applied to Outputs in High-Z State $^{[2]}$ 0.5V to V $_{\rm CC}$ + 0.5V |
|   |
| DC Input Voltage <sup>[2]</sup> –0.5V to $V_{CC}$ + 0.5V                            |
| Current into Outputs (LOW)  |

Electrical Characteristics Over the Operating Range

| Static Discharge Voltage       | >2001V |
|--------------------------------|--------|
| (per MIL-STD-883, Method 3015) |        |
|                                |        |

Latch up Current.....>200 mA

#### **Operating Range**

| Range        | Ambient<br>Temperature | v <sub>cc</sub> |
|--------------|------------------------|-----------------|
| Commercial   | 0°C to +70°C           | $3.3V\pm10\%$   |
| Industrial   | –40°C to +85°C         | $3.3V\pm10\%$   |
| Automotive-A | –40°C to +85°C         | $3.3V\pm10\%$   |

#### -10 (Industrial/ -12 (Industrial) -15 (Industrial) Àuto-A) Parameter Description **Test Conditions** Unit Min Max Min Max Min Max. VOH Output HIGH Voltage V<sub>CC</sub> = Min., 2.4 2.4 2.4 I<sub>OH</sub> = -4.0 mA V<sub>OL</sub> $V_{CC}$ = Min., $I_{OL}$ = 8.0 mA Output LOW Voltage 0.4 0.4 0.4 VIH Input HIGH Voltage 2.0 V<sub>CC</sub> + 0.3 2.0 $V_{CC} + 0.3$ 2.0 $V_{CC} + 0.3$ Input LOW Voltage<sup>[2]</sup> -0.3 -0.3 -0.3 0.8 VIL 0.8 0.8 Input Leakage Current $\mathsf{GND} \leq \mathsf{V_I} \leq \mathsf{V_{CC}}$ -1 -1 -1 μA +1 +1 +1 Ι<sub>ΙΧ</sub> $GND \leq V_{I} \leq V_{CC},$ Output Disabled Output Leakage -1 +1 -1 +1 -1 +1 μΑ I<sub>OZ</sub> Current 80 75 70 V<sub>CC</sub> Operating V<sub>CC</sub> = Max., mΑ lcc Supply Current $I_{OUT} = 0 \text{ mA},$ $f = f_{MAX} = 1/t_{RC}$ Max. $V_{CC}$ , $\overline{CE} \ge V_{IH}$ Automatic CE 15 15 15 mΑ I<sub>SB1</sub> $V_{IN} \ge V_{IH}$ or $V_{IN} \le V_{IL}$ , f = f<sub>MAX</sub> Power down Current -TTL Inputs $\begin{array}{l} \underline{Max}. \ V_{CC}, \\ \overline{CE} \geq V_{CC} - 0.3V, \\ V_{IN} \geq V_{CC} - 0.3V, \\ \text{or } V_{IN} \leq 0.3V, \ \text{f} = 0 \end{array}$ Automatic CE 5 5 5 mΑ I<sub>SB2</sub> Power down Current -CMOS Inputs

#### Capacitance<sup>[3]</sup>

| Parameter        | Description        | Test Conditions                         | Max. | Unit |
|------------------|--------------------|---|------|------|
| C <sub>IN</sub>  | Input Capacitance  | $T_A = 25^{\circ}C, f = 1 \text{ MHz},$ | 8    | pF   |
| C <sub>OUT</sub> | Output Capacitance | V <sub>CC</sub> = 5.0V                  | 8    | pF   |

#### Notes

2.  $V_{IL}$  (min.) = -2.0V for pulse durations of less than 20 ns.

<sup>3.</sup> Tested initially and after any design or process changes that may affect these parameters.





#### Switching Characteristics Over the Operating Range<sup>[5]</sup>

| Parameter                      | Description                         | -10 (Industrial/<br>Auto-A) |     | -12 (Industrial) |     | -15 (Industrial) |     | Unit |
|--------------------------------|-------------------------------------|-----------------------------|-----|------------------|-----|------------------|-----|------|
|                                |                                     | Min                         | Max | Min              | Max | Min              | Max |      |
| Read Cycle                     | ·                                   |                             |     |                  |     |                  |     |      |
| t <sub>RC</sub>                | Read Cycle Time                     | 10                          |     | 12               |     | 15               |     | ns   |
| t <sub>AA</sub>                | Address to Data Valid               |                             | 10  |                  | 12  |                  | 15  | ns   |
| t <sub>OHA</sub>               | Data Hold from Address Change       | 3                           |     | 3                |     | 3                |     | ns   |
| t <sub>ACE</sub>               | CE LOW to Data Valid                |                             | 10  |                  | 12  |                  | 15  | ns   |
| t <sub>DOE</sub>               | OE LOW to Data Valid                |                             | 5   |                  | 6   |                  | 7   | ns   |
| t <sub>LZOE</sub>              | OE LOW to Low Z                     | 0                           |     | 0                |     | 0                |     | ns   |
| t <sub>HZOE</sub>              | OE HIGH to High Z <sup>[6, 7]</sup> |                             | 5   |                  | 6   |                  | 7   | ns   |
| t <sub>LZCE</sub>              | CE LOW to Low Z <sup>[7]</sup>      | 3                           |     | 3                |     | 3                |     | ns   |
| t <sub>HZCE</sub>              | CE HIGH to High Z <sup>[6, 7]</sup> |                             | 5   |                  | 6   |                  | 7   | ns   |
| t <sub>PU</sub> <sup>[8]</sup> | CE LOW to Power Up                  | 0                           |     | 0                |     | 0                |     | ns   |
| t <sub>PD</sub> <sup>[8]</sup> | CE HIGH to Power Down               |                             | 10  |                  | 12  |                  | 15  | ns   |
| Write Cycle                    | 9, 10]                              |                             |     |                  |     |                  |     |      |
| t <sub>WC</sub>                | Write Cycle Time                    | 10                          |     | 12               |     | 15               |     | ns   |
| t <sub>SCE</sub>               | CE LOW to Write End                 | 8                           |     | 9                |     | 10               |     | ns   |
| t <sub>AW</sub>                | Address Setup to Write End          | 8                           |     | 9                |     | 10               |     | ns   |
| t <sub>HA</sub>                | Address Hold from Write End         | 0                           |     | 0                |     | 0                |     | ns   |
| t <sub>SA</sub>                | Address Setup to Write Start        | 0                           |     | 0                |     | 0                |     | ns   |
| t <sub>PWE</sub>               | WE Pulse Width                      | 7                           |     | 8                |     | 10               |     | ns   |
| t <sub>SD</sub>                | Data Setup to Write End             | 5                           |     | 6                |     | 8                |     | ns   |
| t <sub>HD</sub>                | Data Hold from Write End            | 0                           |     | 0                |     | 0                |     | ns   |
| t <sub>LZWE</sub>              | WE HIGH to Low Z <sup>[7]</sup>     | 3                           |     | 3                |     | 3                |     | ns   |
| t <sub>HZWE</sub>              | WE LOW to High Z <sup>[6, 7]</sup>  |                             | 5   |                  | 6   |                  | 7   | ns   |

Notes

8. This parameter is guaranteed by design and is not tested.

9.

The internal write time of the memory is defined by the overlap of CE LOW and WE LOW. CE and WE must be LOW to initiate a write, and the transition of any of these signals can terminate the write. The input data setup and hold timing should be referenced to the leading edge of the signal that terminates the write.

10. The minimum write cycle time for Write Cycle no. 3 (WE controlled, OE LOW) is the sum of t<sub>HZWE</sub> and t<sub>SD</sub>.

<sup>4.</sup> AC characteristics (except High-Z) for all speeds are tested using the Thevenin load shown in section (a) in Figure 3. High-Z characteristics are tested for all speeds using the test load shown in section (c) in Figure 3.

<sup>5.</sup> Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V.

t<sub>HZOE</sub>, t<sub>HZCE</sub>, and t<sub>HZWE</sub> are specified with a load capacitance of 5 pF as in part (d) of Figure 3. Transition is measured ±500 mV from steady-state voltage. 6. 7. At any given temperature and voltage condition, t<sub>HZCE</sub> is less than t<sub>LZCE</sub>, t<sub>HZOE</sub> is less than t<sub>LZOE</sub>, and t<sub>HZWE</sub> is less than t<sub>LZWE</sub> for any given device.



#### **Switching Waveforms**

Figure 4. Read Cycle No. 1<sup>[11, 12]</sup>











#### Notes

- 11. Device is continuously selected.  $\overline{OE}$ ,  $\overline{CE} = V_{|L}$ . 12. WE is HIGH for read cycle.

Address valid prior to or coincident with CE transition LOW.
 Data I/O is high impedance if OE = V<sub>IL</sub>.
 If CE goes HIGH simultaneously with WE going HIGH, the output remains in a high impedance state.



#### Switching Waveforms (continued)





Figure 8. Write Cycle No. 3 (WE Controlled, OE LOW)



#### **Truth Table**

| CE | OE | WE | I/O <sub>0</sub> –I/O <sub>7</sub> | Mode                       | Power                      |
|----|----|----|------------------------------------|----------------------------|----------------------------|
| Н  | Х  | Х  | High Z                             | Power Down                 | Standby (I <sub>SB</sub> ) |
| L  | L  | Н  | Data Out                           | Read                       | Active (I <sub>CC</sub> )  |
| L  | Х  | L  | Data In                            | Write                      | Active (I <sub>CC</sub> )  |
| L  | Н  | Н  | High Z                             | Selected, Outputs Disabled | Active (I <sub>CC</sub> )  |

Note

16. During this period the I/Os are in the output state and input signals should not be applied.



## **Ordering Information**

| Speed<br>(ns) | Ordering Code       | Package<br>Diagram | Package Type                        | Operating<br>Range |
|---------------|---------------------|--------------------|-------------------------------------|--------------------|
| 10            | CY7C1019CV33-10VC   | 51-85033           | 32-pin 400-Mil Molded SOJ           | Commercial         |
|               | CY7C1019CV33-10ZXC  | 51-85095           | 32-pin TSOP II (Pb-Free)            |                    |
|               | CY7C1019CV33-10ZXI  |                    | 32-pin TSOP II (Pb-Free)            | Industrial         |
|               | CY7C1019CV33-10ZXA  | 51-85095           | 32-pin TSOP II (Pb-Free)            | Automotive-A       |
| 12            | CY7C1019CV33-12VC   | 51-85033           | 32-pin 400-Mil Molded SOJ           | Commercial         |
|               | CY7C1019CV33-12ZC   | 51-85095           | 32-pin TSOP II                      |                    |
|               | CY7C1019CV33-12ZXC  |                    | 32-pin TSOP II (Pb-Free)            |                    |
|               | CY7C1019CV33-12VI   | 51-85033           | 32-pin 400-Mil Molded SOJ           | Industrial         |
|               | CY7C1019CV33-12BVXI | 51-85150           | 48-ball VFBGA (Pb-Free)             |                    |
| 15            | CY7C1019CV33-15VC   | 51-85033           | 32-pin 400-Mil Molded SOJ           | Commercial         |
|               | CY7C1019CV33-15VXC  | 51-85033           | 32-pin 400-Mil Molded SOJ (Pb-Free) |                    |
|               | CY7C1019CV33-15ZXC  | 51-85095           | 32-pin TSOP II (Pb-Free)            |                    |
|               | CY7C1019CV33-15ZXI  | 51-85095           | 32-pin TSOP II (Pb-Free)            | Industrial         |

# Package Diagrams





Document #: 38-05130 Rev. \*G



Figure 10. 32-Pin TSOP II









TOP VIEW



51-85150-\*D





#### **Document History Page**

|      | Document Title: CY7C1019CV33 1 Mbit (128K x 8) Static RAM<br>Document Number: 38-05130 |                    |                    |   |  |  |
|------|--|--------------------|--------------------|---|--|--|
| REV. | ECN NO.  | Submission<br>Date | Orig. of<br>Change | Description of Change   |  |  |
| **   | 109245   | 12/16/01           | HGK                | New Data Sheet  |  |  |
| *A   | 113431   | 04/10/02           | NSL                | AC Test Loads split based on speed  |  |  |
| *В   | 115047   | 08/01/02           | HGK                | Added TSOP II Package and I Temp. Improved I <sub>CC</sub> limits   |  |  |
| *C   | 119796   | 10/11/02           | DFP                | Updated standby current from 5 nA to 5 mA   |  |  |
| *D   | 123030   | 12/17/02           | DFP                | Updated Truth Table to reflect single Chip Enable option  |  |  |
| *E   | 419983   | See ECN            | NXR                | Added 48-ball VFBGA Package<br>Added lead-free parts in Ordering Information Table<br>Replaced Package Name column with Package Diagram in the Ordering<br>Information Table  |  |  |
| *F   | 493543   | See ECN            | NXR                | Removed 8 ns speed bin from Product offering<br>Added note #1 on page #2<br>Changed the description of $I_{ X}$ from Input Load Current to<br>Input Leakage Current in DC Electrical Characteristics table<br>Removed $I_{OS}$ parameter from DC Electrical Characteristics table<br>Updated Ordering Information |  |  |
| *G   | 2761448  | 09/09/2009         | VKN                | Included Automotive-A information   |  |  |

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Revised September 08, 2009

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